



### **Ultrafast Rectifier**

## **MUR2040CT**

#### FEATURES

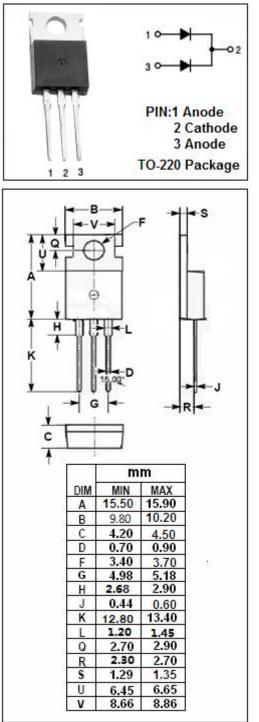
- Guarding for over voltage protection
- · Dual rectifier construction, positive center tap
- · Metal of silicon rectifier, majority carrier conduction
- · Low forward voltage, high efficiency
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### APPLICATIONS

- Switching power supply
- Power switching circuits

### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL             | PARAMETER  | VALUE    | UNIT |
|--------------------|--|----------|------|
| Vrrm<br>Vrwm<br>Vr | Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage                         | 400      | V    |
| I <sub>F(AV)</sub> | Average Rectified Forward Current Per Leg<br>Total device  | 10<br>20 | A    |
| IFSM               | Nonrepetitive Peak Surge Current<br>(Surge applied at rated load conditions half-<br>wave, single phase, 60Hz) | 150      | A    |
| P <sub>D</sub>     | Maximum power dissipation  | 76       | W    |
| TJ                 | Junction Temperature   | -55~150  | °C   |
| T <sub>stg</sub>   | Storage Temperature Range  | -55~150  | °C   |



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### **INCHANGE SEMICONDUCTOR**

### Fast Recovery Rectifier

# MUR2040CT

### THERMAL CHARACTERISTICS

| SYMBOL              | PARAMETER                            | МАХ | UNIT |
|---------------------|--------------------------------------|-----|------|
| R <sub>th j-c</sub> | Thermal Resistance, Junction to Case |     | °C/W |

### ELECTRICAL CHARACTERISTICS(Ta=25℃) (Pulse Test: Pulse Width=300 µ s,Duty Cycle≤2%)

| SYMBOL          | PARAMETER                             | CONDITIONS   | MAX       | UNIT |
|-----------------|---------------------------------------|--|-----------|------|
| VF              | Maximum Instantaneous Forward Voltage | I <sub>F</sub> = 10A ;Tj=25°C  | 1.3       | V    |
| I <sub>R</sub>  | Maximum Instantaneous Reverse Current | V <sub>R</sub> = V <sub>RWM;</sub> Tj=125°C<br>V <sub>R</sub> = V <sub>RWM</sub> | 250<br>10 | μA   |
| t <sub>rr</sub> | Maximum Reverse Recovery Time         | IF =1A;  | 50        | ns   |

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